RENESAS High-Performance 1.8V/2.5V/3.3V Crystal Input to LVCMOS Clock Fanout Buffer with OE

DATASHEET

5P8390x

Description

The 5P8390x is a high performance, 1-to-4/6/8 crystal input to LVCMOS fanout buffer with output enable pins. This device accepts a fundamental mode crystal from 10MHz to 40MHz and outputs LVCMOS clocks with best-in-class phase noise performance.

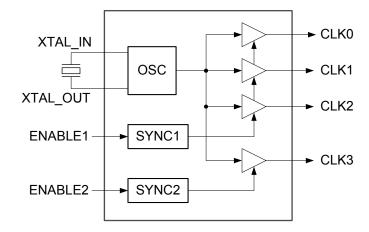
The 5P8390x family (5P83904, 5P83905, and 5P83908) features a synchronous glitch-free Output Enable function to eliminate any intermediate incorrect output clock cycles when enabling or disabling outputs. It comes in standard TSSOP packages or small QFN packages and can operate from 1.8V to 3.3V supplies.

Features

- 4/6/8 copies of LVCMOS output clocks with best-in-class phase noise performance
- Phase Noise:

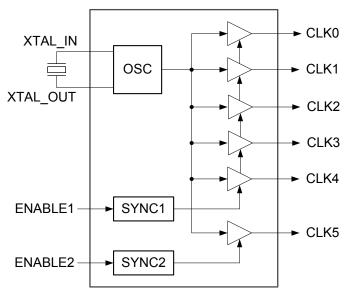
Offset Noise Power (3.3V)

- 100Hz: -131 dBc/Hz
- 1KHz: -145 dBc/Hz
- 10KHz: -154 dBc/Hz
- 100KHz: -161 dBc/Hz
- Operating power supply modes:
 - Full 3.3V, 2.5V, 1.8V
 - Mixed 3.3V core/2.5V output operating supply
 - Mixed 3.3V core/1.8V output operating supply
 - Mixed 2.5V core/1.8V output operating supply
- Crystal Oscillator Interface
- Synchronous Output Enable
- Packaged in 16-, 20-pin TSSOP and QFN packages (Pb free, fully RoHS compliant)
- Extended (-40°C to +105°C) temperature range

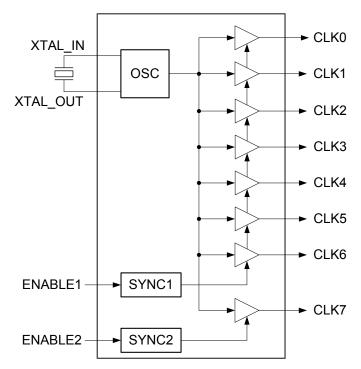


5P83904 Block Diagram

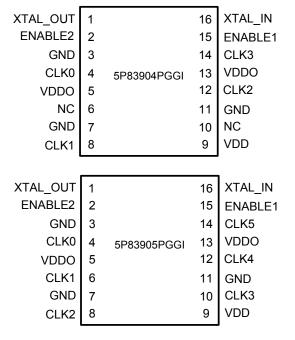
5P83905 Block Diagram



5P83908 Block Diagram

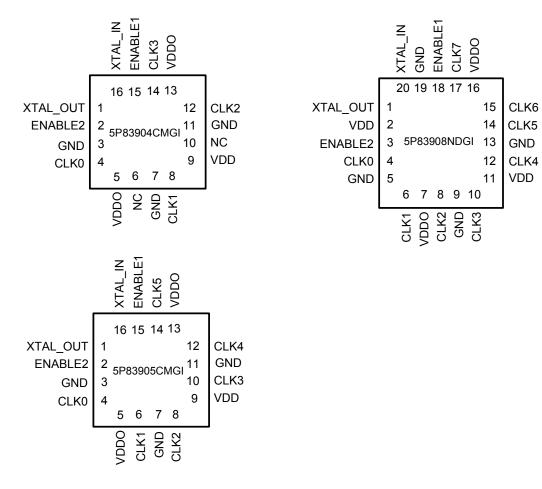


Pin Assignments for TSSOP Packages



XTAL_OUT	1		20	XTAL_IN
VDD	2		19	GND
ENABLE2	3		18	ENABLE1
CLK0	4		17	CLK7
GND	5	5P83908PGGI	16	VDDO
CLK1	6		15	CLK6
VDDO	7		14	CLK5
CLK2	8		13	GND
GND	9		12	CLK4
CLK3	10		11	VDD
				•

Pin Assignments for QFN Packages



Pin Descriptions

Pin Name		Pin Numbe	r	Din Turno	Din Description
	5P83904	5P83905	5P83908	Pin Type	Pin Description
XTAL_IN	16	16	20	Input	Oscillator Input from Crystal.
XTAL_OUT	1	1	1	Input	Oscillator Output to drive Crystal.
VDD	9	9	2, 11	Power	Positive power supply for core.
VDDO	5, 13	5, 13	7, 16	Power	Positive power supply for outputs.
GND	3, 7, 11	3, 7, 11	5, 9, 13, 19	Power	Power supply ground.
ENABLE1	15	15	18	Input	Output Enable pin. Please see below Output Enable Function Table. Active High. Internal pull-up.
ENABLE2	2	2	3	Input	Output Enable pin. Please see below Output Enable Function Table. Active High. Internal pull-up.
CLK0	4	4	4	Output	LVCMOS Clock Output 0. Voltage set by VDDO.
CLK1	8	6	6	Output	LVCMOS Clock Output 1. Voltage set by VDDO.
CLK2	12	8	8	Output	LVCMOS Clock Output 2. Voltage set by VDDO.
CLK3	14	10	10	Output	LVCMOS Clock Output 3. Voltage set by VDDO.
CLK4		12	12	Output	LVCMOS Clock Output 4. Voltage set by VDDO.
CLK5		14	14	Output	LVCMOS Clock Output 5. Voltage set by VDDO.
CLK6	_	_	15	Output	LVCMOS Clock Output 6. Voltage set by VDDO.
CLK7		—	17	Output	LVCMOS Clock Output 7. Voltage set by VDDO.
NC	6, 10	_	—	NC	No connect.

Output Enable Function Table

ENABLE1	ENABLE2	5P83904 CLK0-2	5P83905 CLK0-4	5P83908 CLK0-6	5P83904 CLK3	5P83905 CLK5	5P83908 CLK7
0	0	Low	Low	Low	Low	Low	Low
0	1	Low	Low	Low	Active	Active	Active
1	0	Active	Active	Active	Low	Low	Low
1(default)	1(default)	Active	Active	Active	Active	Active	Active

Absolute Maximum Ratings

Stresses above the ratings listed below can cause permanent damage to the 5P8390x. These ratings, which are standard values for IDT commercially rated parts, are stress ratings only. Functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods can affect product reliability. Electrical parameters are guaranteed only over the recommended operating temperature range.

Item	Rating
Supply Voltage, VDD	3.465V
Output Enable and All Outputs	-0.4 V to VDD+0.5 V
CLKIN	-0.4 V to 3.465V
Ambient Operating Temperature (extended)	-40 to +105°C
Storage Temperature	-65 to +150°C
Junction Temperature	125°C
Soldering Temperature	260°C

Recommended Operation Conditions

Parameter	Min.	Тур.	Max.	Units
Ambient Operating Temperature (extended)	-40		+105	°C
Power Supply Voltage (measured in respect to GND)	+1.71		+3.465	V

DC Electrical Characteristics

(VDD = 1.8V, 2.5V, 3.3V)

VDD=1.8V ±5%, Ambient temperature -40° to +105°C, unless stated otherwise

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Input High Voltage	V _{IH}	XTAL_IN, ENABLE1/2 pins	0.7xVDD			V
Input Low Voltage	V _{IL}	XTAL_IN, ENABLE1/2 pins			0.3xVDD	V
Output High Voltage	V _{OH}	I _{OH} = -4 mA	1.65		1.85	V
Output Low Voltage	V _{OL}	I _{OL} = 4 mA	0.03		0.05	V
Nominal Output Impedance	Z _O			14		Ω
Operating Supply Current	L	· · · · · ·		1	l	4
5P83904		Outputs On, 25MHz with No Load		8.9		
5P83905	IDD	Outputs On, 25MHz with No Load		9.0		mA
5P83908		Outputs On, 25MHz with No Load		9.2		

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Input High Voltage	V _{IH}	XTAL_IN, ENABLE1/2 pins	0.7xVDD			V
Input Low Voltage	V _{IL}	XTAL_IN, ENABLE1/2 pins			0.3xVDD	V
Output High Voltage	V _{OH}	I _{OH} = -4 mA	2.31		2.58	V
Output Low Voltage	V _{OL}	I _{OL} = 4 mA	0.03		0.05	V
Nominal Output Impedance	Z _O			14		Ω
Operating Supply Current	I	· · · · · · · · · · · · · · · · · · ·				
5P83904		Outputs On, 25MHz with No Load		10.6		
5P83905	IDD	Outputs On, 25MHz with No Load		10.7		mA
5P83908		Outputs On, 25MHz with No Load		10.8		

VDD=2.5 V ±5%, Ambient temperature -40° to +105°C, unless stated otherwise

VDD=3.3 V ±5% , Ambient temperature -40° to +105°C, unless stated otherwise

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Input High Voltage, CLKIN	V _{IH}	XTAL_IN, ENABLE1/2 pins	0.7xVDD			V
Input Low Voltage, CLKIN	V _{IL}	XTAL_IN, ENABLE1/2 pins			0.3xVDD	V
Output High Voltage	V _{OH}	I _{OH} = -4 mA	3.09		3.43	V
Output Low Voltage	V _{OL}	I _{OL} = 4 mA	0.03		0.04	V
Nominal Output Impedance	Z _O			14		Ω
Operating Supply Current		•			•	<u>.</u>
5P83904		Outputs On, 25MHz with No Load		12.1		
5P83905	IDD	Outputs On, 25MHz with No Load		12.2		mA
5P83908		Outputs On, 25MHz with No Load		12.3		

AC Electrical Characteristics (VDD = 1.8V, 2.5V, 3.3V)

VDD = 1.8V ±5%, Ambient Temperature -40° to +1	105°C, unless stated otherwise
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Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Input Frequency	f _{MAX}	Input Frequency Crystal	8		40	MHz
		Input Frequency Clock	DC		200	
Delay for Output Enable / Disable Time ENABLEx to BCLKn	t _{EN /} t _{DIS}				3	cycles
Duty Cycle	t _{DC}		45		55	ns
Output to Output Skew	t _{SKEWO-O}			25	65	ps
Phase Noise	Фnoise	f _{OUT} = 25 MHz 100 Hz off Carrier		-121.1974		dBc/Hz
		f _{OUT} = 25 MHz 1 kHz off Carrier		-132.1742		
		f _{OUT} = 25 MHz 10 kHz off Carrier		-143.8058		
		f _{OUT} = 25 MHz 100 kHz off Carrier		-155.2978		
RMS Phase Jitter	t _{JIT} (Φ)	25MHz carrier, Integration Range: 12kHz-20MHz		0.279		ps
Output Rise/Fall Time	t _{R /} t _F	20% to 80%			0.95	ns
Device to Device Skew					200	ps
Propagation Delay		freq, LVCMOS INPUT	2.5	3.1	6	ns

VDD = 2.5 V ±5%, Ambient Temperature -40° to +105°C, unless stated otherwise

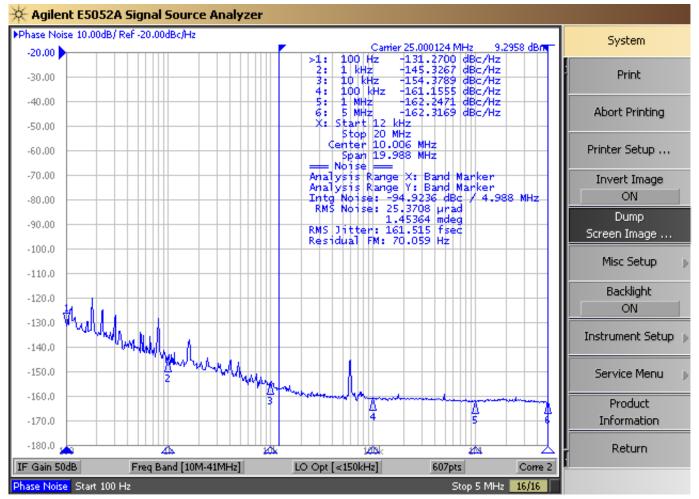
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Input Frequency	f _{MAX}	Input Frequency Crystal	8		40	MHz
		Input Frequency Clock	DC		200	
Delay for Output Enable / Disable Time ENABLEx to BCLKn	t _{EN /} t _{DIS}				3	cycles
Duty Cycle	t _{DC}		45		55	ns
Output to Output Skew	t _{SKEWO-O}			25	65	ps
Phase Noise	Φnoise	f _{OUT} = 25 MHz 100 Hz off Carrier		-131.26		dBc/Hz
		f _{OUT} = 25 MHz 1 kHz off Carrier		-139.2177		
		f _{OUT} = 25 MHz 10 kHz off Carrier		-149.5185		
		f _{OUT} = 25 MHz 100 kHz off Carrier		-158.7531		
RMS Phase Jitter	t _{JIT} (Φ)	25MHz carrier, Integration Range: 12kHz-20MHz		0.2		ps
Output Rise/Fall Time	t _{R /} t _F	20% to 80%			0.9	ns
Device to Device Skew					200	ps
Propagation Delay		freq, LVCMOS INPUT	2.5	3.6	6	ns

VDD = 3.3 V ±5%, Ambient Temperature -40° to +105°C, unless stated otherwise

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Input Frequency	f _{MAX}	Input Frequency Crystal	8		40	MHz
		Input Frequency Clock	DC		200	
Delay for Output Enable / Disable Time ENABLEx to BCLKn	t _{EN /} t _{DIS}				3	cycles
Duty Cycle	t _{DC}		45		55	ns
Output to Output Skew	t _{SKEWO-O}			25	65	ps

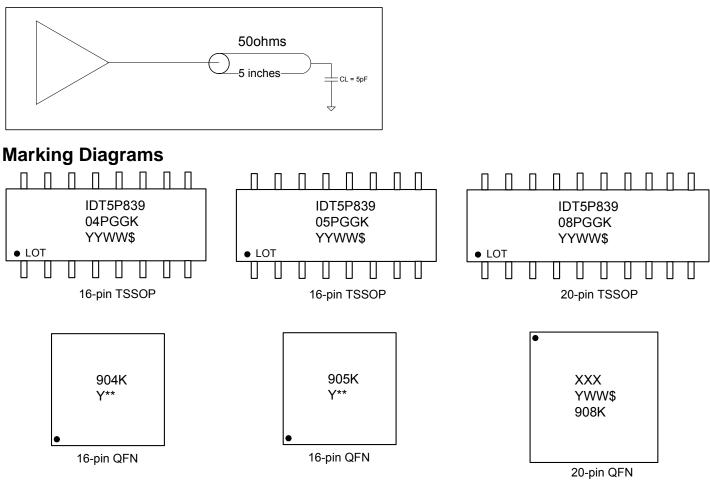
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Phase Noise	Φnoise	f _{OUT} = 25 MHz 100 Hz off Carrier		-131.27		dBc/Hz
		f _{OUT} = 25 MHz 1 kHz off Carrier		-145.3267		
		f _{OUT} = 25 MHz 10 kHz off Carrier		-154.3789		
		f _{OUT} = 25 MHz 100 kHz off Carrier		-161.1555		
RMS Phase Jitter	t _{JIT} (Φ)	25MHz carrier, Integration Range: 12kHz-20MHz		0.16		ps
Output Rise/Fall Time	t _{R /} t _F	20% to 80%			0.85	ns
Device to Device Skew					200	ps
Propagation Delay		freq, LVCMOS INPUT	2.5	2.9	6	ns

Phase Noise Plots



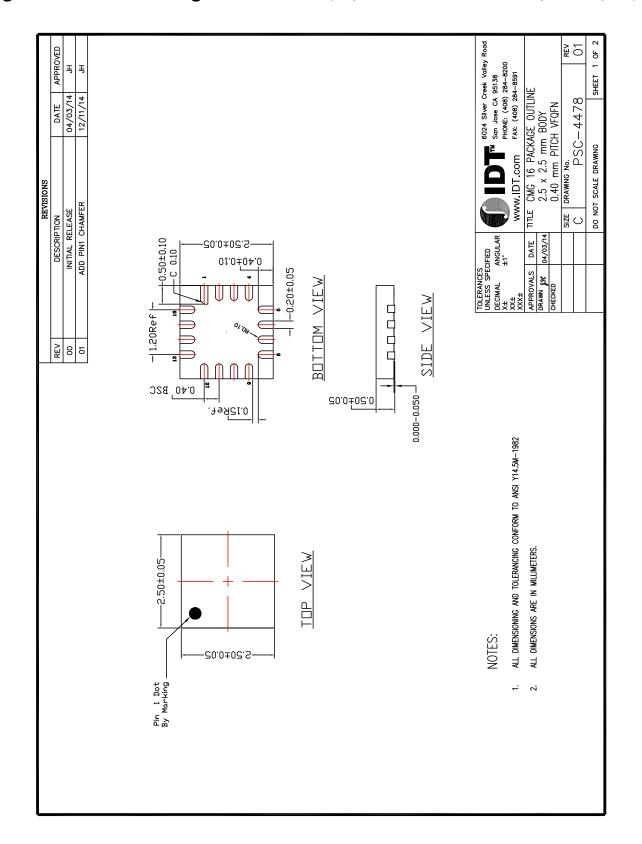
The phase noise plots above show the low Additive Jitter of the 5P8390x high-performance buffer. With an integration range of 12kHz to 20MHz, the reference input has about 58.9fs of RMS phase jitter while the output of 5P8390x has about 70.9fs of RMS phase jitter. This results in a low Additive Phase Jitter of only 39fs.

Test Load and Circuit

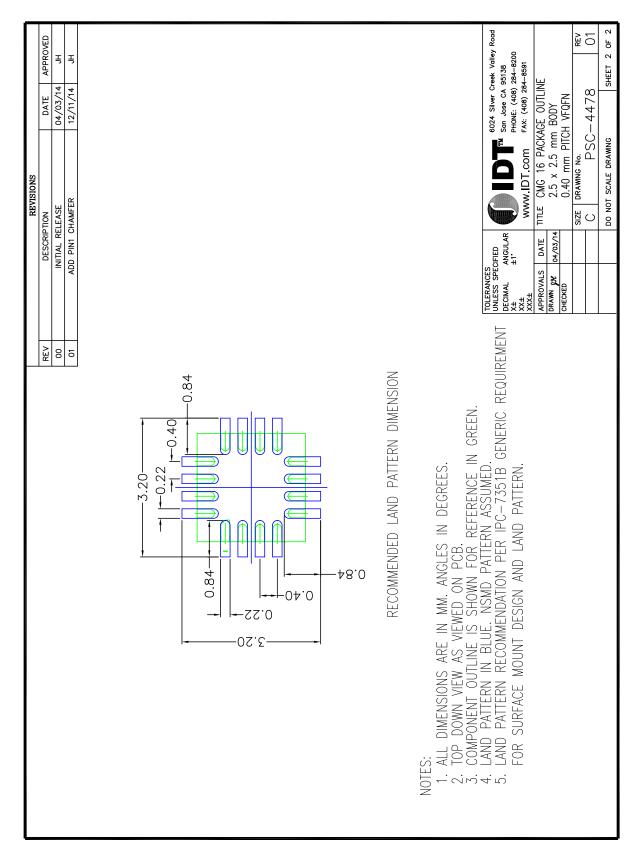


Notes:

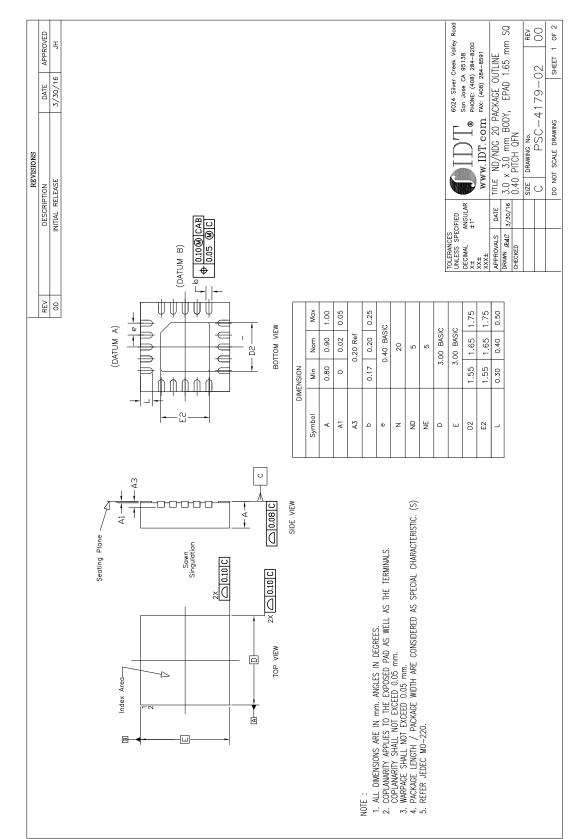
- 1. "**" is the lot sequence.
- 2. "XXX" denotes the last three characters of the Asm lot (20-pin QFN only).
- 3. "YYWW", "YWW", "YW", or "Y" is the last digit(s) of the year and week that the part was assembled.
- 4. "\$" denotes the mark code.
- 5. "LOT" denotes lot number.
- 6. "G" after the two-letter package code denotes RoHS compliant package.
- 7. "I" denotes extended temperature range device.
- 8. Bottom marking: country of origin (TSSOP only).



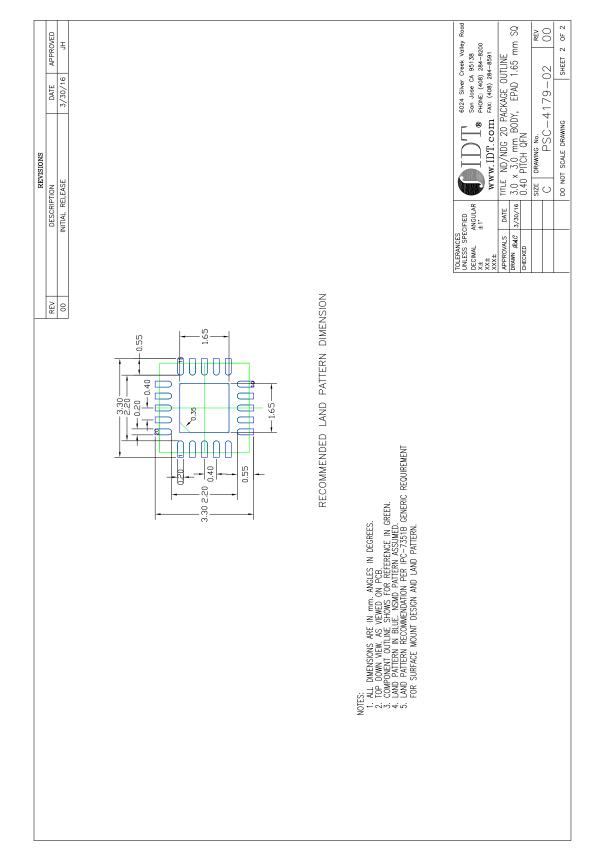
Package Outline and Package Dimensions (16-pin QFN, 2.5mm x 2.5mm Body, 0.4mm pitch)



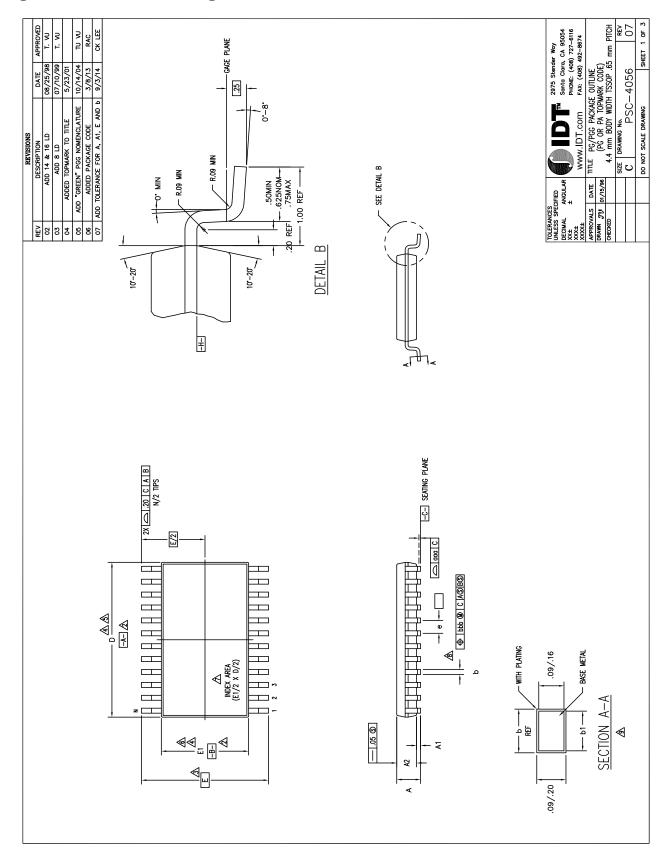
Package Outline and Package Dimensions, cont. (16-pin QFN, 2.5mm x 2.5mm Body, 0.4mm pitch)



Package Outline and Package Dimensions (20-pin QFN, 3mm x 3mm Body, 0.4mm pitch)



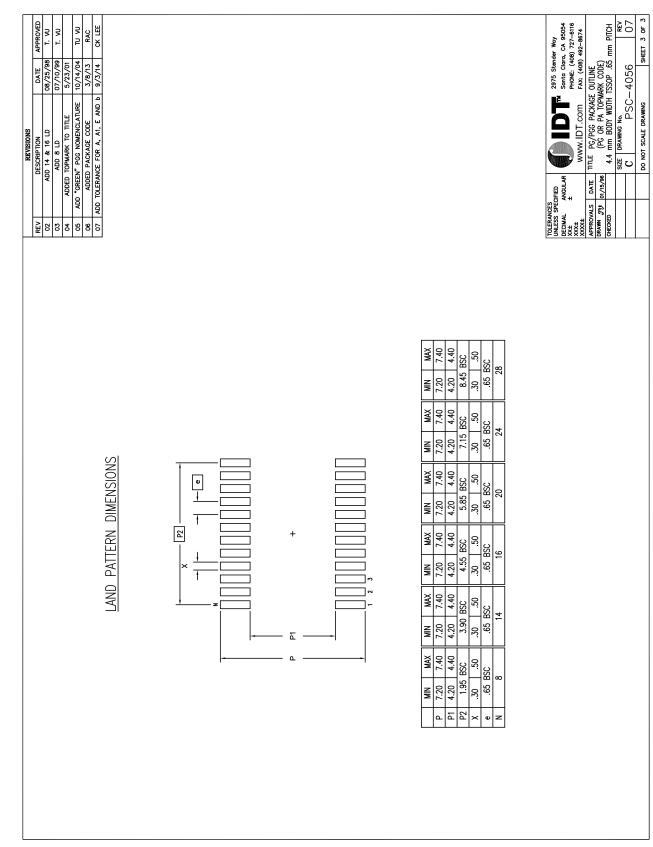
Package Outline and Package Dimensions, cont. (20-pin QFN, 3mm x 3mm Body, 0.4mm pitch)



Package Outline and Package Dimensions (8-, 14-, 16-, 20-pin TSSOP)

	¥	/25/98 T. W			+	14 CK LEE																														2975 Stender Way	Santa Clara, CA 95054 PHONE: (408) 727–6116 FAX: (408) 492–8674	TITLE PG/PGC PACKAGE OUTLINE (PG OR PA TOPMARK CODE)	.65 mm PITCH											
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Package Outline and Package Dimensions, cont. (8-, 14-, 16-, 20-pin TSSOP)



Package Outline and Package Dimensions, cont. (8-, 14-, 16-, 20-pin TSSOP)

Ordering Information

Part / Order Number	Marking	Shipping Packaging	Package	Temperature
5P83904PGGK	see page 9	Tubes	16-pin TSSOP	-40° to +105°C
5P83904PGGK8		Tape and Reel	16-pin TSSOP	-40° to +105°C
5P83904CMGK		Cut Tape	16-pin QFN	-40° to +105°C
5P83904CMGK8		Tape and Reel	16-pin QFN	-40° to +105°C
5P83905PGGK		Tubes	16-pin TSSOP	-40° to +105°C
5P83905PGGK8		Tape and Reel	16-pin TSSOP	-40° to +105°C
5P83905CMGK		Cut Tape	16-pin QFN	-40° to +105°C
5P83905CMGK8		Tape and Reel	16-pin QFN	-40° to +105°C
5P83908PGGK		Tubes	20-pin TSSOP	-40° to +105°C
5P83908PGGK8		Tape and Reel	20-pin TSSOP	-40° to +105°C
5P83908NDGK		Tubes	20-pin QFN	-40° to +105°C
5P83908NDGK8		Tape and Reel	20-pin QFN	-40° to +105°C

"G" after the two-letter package code denotes Pb-Free configuration, RoHS compliant. "K" denotes extended temperature range.

Revision History

Rev.	Date	Originator	Description of Change
А	07/11/16	H.G.	Release to final.
В	10/05/16	Y.G.	 Update "Propagation Delay" typical values per latest characterization data. Update "Output Rise/Fall" maximum values per latest characterization data.



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Corporate Headquarters

TOYOSU FORESIA, 3-2-24 Toyosu, Koto-ku, Tokyo 135-0061, Japan www.renesas.com

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